# NSN 5961-01-340-1357

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-340-1357

# Inclosure Material:

Metal and ceramic

## **Overall Length:**

Between 0.890 inches and 0.910 inches

# **Overall Height:**

Between 0.200 inches and 0.230 inches

## **Overall Width:**

0.830 inches

#### **End Application:**

Radar set an/sps-40d

## Mounting Facility Quantity:

2

## Internal Configuration:

Junction contact

#### Mounting Method:

Slot

# Features Provided:

Gold plated leads and burn in

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 25.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage,

static, collector open and 60.0 collector to emitter voltage, dc with base short-circuited to emitter

# **Current Rating Per Characteristic:**

5.40 amperes source cutoff current

## **Power Rating Per Characteristic:**

87.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Precious Material And Location:**

Terminal surfaces gold

#### **Precious Material:**

Gold

## **Terminal Type And Quantity:**

1 flange and 2 ribbon

Shelf Life:

N/a

#### Unit Of Measure:

---

Demilitarization:

# **NSN 5961-01-340-1357** Transistor - Page 2 of 2

Fiig: A110a0

